EE 435

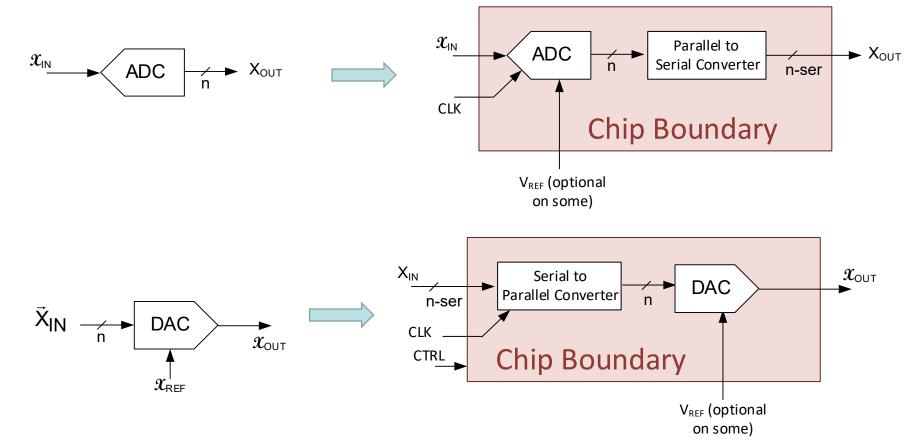
Lecture 39

Data Converters Statistical Characterization

Review from Last Lecture

Actual Catalog Data Converter Parts

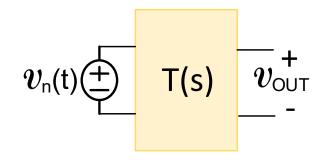
- Often (not always) digital interface with data converter is serial
- Significantly Reduces pin count
- Interfaces usually follow standard protocols
- Challenge in data converter design almost always in the data converter itself
- Multiple channels often available and these usually use single converter and MUX



Noise in DACs

Resistors and transistors contribute device noise but what about charge redistribution DACs?

Noise in linear circuits:



Due to any noise voltage source:

$$S_{_{\scriptscriptstyle VOUT}} = S_{_{\scriptscriptstyle V_{\scriptscriptstyle n}}} \left| T_{_{\scriptscriptstyle n}} \left(j\omega
ight)
ight|^2$$

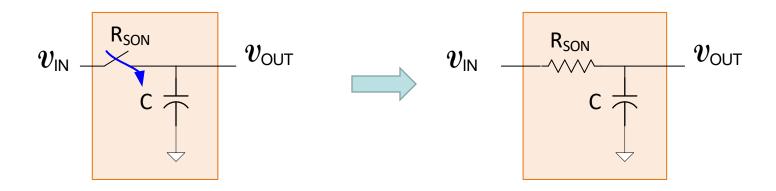
$$oldsymbol{v}_{\scriptscriptstyle OUT_{\scriptscriptstyle RMS}} = \sqrt{\int\limits_{\scriptscriptstyle \mathsf{f}=0}^{\infty} S_{\scriptscriptstyle \scriptscriptstyle VOUT}} \mathsf{df}$$

Thus:

$$oldsymbol{\mathcal{V}_{\scriptscriptstyle OUT_{\scriptscriptstyle RMS}}} = \sqrt{\int\limits_{\scriptscriptstyle \mathsf{f=0}}^{\infty} S_{\scriptscriptstyle \scriptscriptstyle V_{\scriptscriptstyle OUT}} \mathrm{df}} = \sqrt{\int\limits_{f=0}^{\infty} S_{\scriptscriptstyle \scriptscriptstyle V_{\scriptscriptstyle n}} \left|T_{\scriptscriptstyle n}\left(j\omega
ight)\right|^{\scriptscriptstyle 2} \mathrm{df}}$$

Sample and Hold Circuits

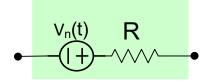
During Track Mode



When switch is opened to take sample, noise on C is captured on C (superimposed on signal)

This noise becomes input noise to the ADC

Recall noise in resistor modeled as noise voltage source in series with R



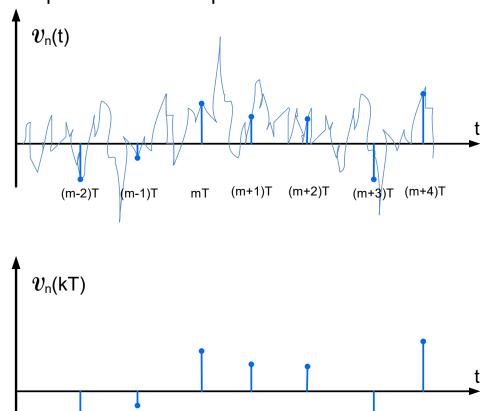
Review from Last Lecture

Sample and Hold Circuits

(m-2)T

(m-1)T

T is the period of the sampler



 $v_{\mathsf{n}}(\mathsf{mT})$ is a discrete-time sequence obtained by sampling continuous-time noise waveform

(m+1)T

(m+2)T

(m+3)T (m+4)T

RMS value of noise input to pipelined ADC is that of the discrete time noise sequence

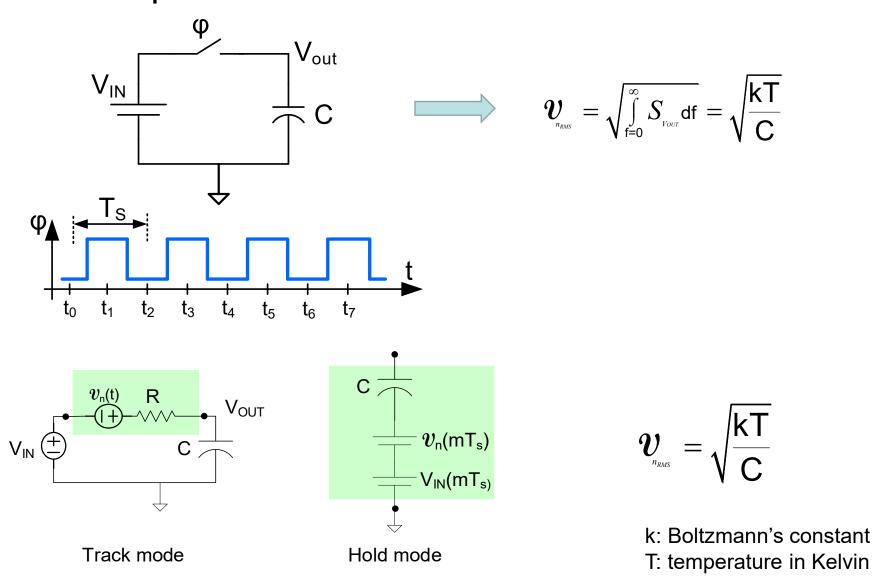
Review from Last Lecture

Theorem 1 If v(t) is a continuous-time zero-mean noise source and v(kT) is a sampled version of v(t) sampled at times T, 2T, then the RMS value of the continuous-time waveform is the same as that of the sampled version of the waveform. This can be expressed as $v(t) = \hat{v}(t)$

Theorem 2 If v(t) is a continuous-time zero-mean noise signal and v(t) is a sampled version of v(t) sampled at times T, 2T, then the standard deviation of the random variable v(t), denoted as σ_{v} satisfies the expression $\sigma_{v} = v(t) = v(t)$

From Theorem 1 we obtain the RMS value of the switched capacitor sampler

Sample and Hold Circuits



RMS noise at output of basic SC S/H is independent of R but dependent upon C

Methods of Characterizing how Random Variables Affect Performance

- Analytical Statistical Formulation and Analysis
- MATLAB Simulations (often using Monte-Carlo Analysis)
- Spectre/Spice Monte-Carlo Simulations
- Ignore Effects of Random Effects

How important is statistical characterization of data converters?

Example: 7-bit FLASH ADC with R-string DAC

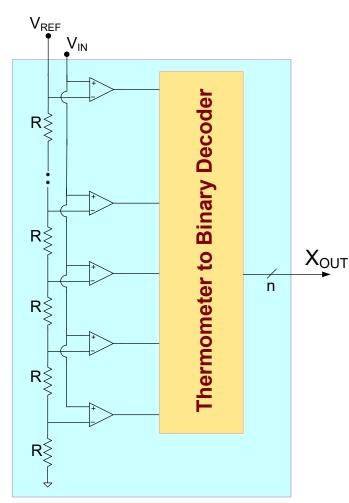
Assume R-string is ideal, V_{REF} =1V and V_{OS} for each comparator must be at most +/- $\frac{1}{2}$ LSB

Why this assumption?

Note: this is a much different performance requirement than requiring that INL< ½ LSB and would not be part of a standard specification but we will see that it is analytical tractable and gives an appreciation for the importance of statistical analysis

Case 1

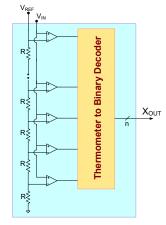
Determine the yield if V_{OS} has a Gaussian distribution (Normal) with zero mean and a standard deviation of 5mV



Example: 7-bit FLASH ADC with R-string DAC

Assume R-string is ideal, V_{REF} =1V and V_{OS} for each comparator must be at most +/- $\frac{1}{2}$ LSB

Case 1

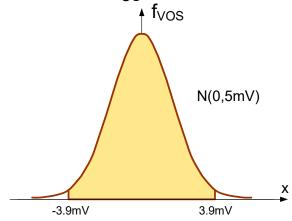


Determine the yield if V_{OS} has a Gaussian distribution (Normal) with zero mean and a standard deviation of 5mV

$$\frac{1}{2}$$
 LSB = $\frac{1}{(2^{(7+1)})}$ =3.9mV

The probability that a single comparator meets the V_{OS} requirement is given by

$$P_{COMP} = \int_{-3.9mV}^{3.9mV} f_{VOS} dV$$

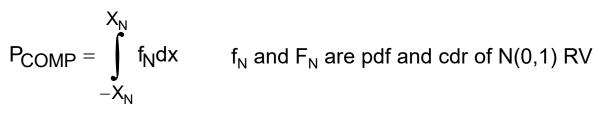


Example: 7-bit FLASH ADC with R-string DAC Assume V_{OS} is zero-mean gaussian

Case 1
$$\sigma_{VOS}$$
=5mV

$$P_{COMP} = \int_{-3.9mV}^{3.9mV} f_{VOS} dV$$

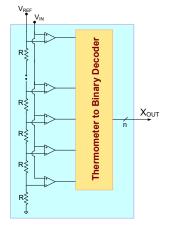
Define $X_N = V_{OS}/\sigma$ Since $\mu = 0$, this will make $X_N : N(0,1)$



 $X_N = 3.9 \text{mV} / 5 \text{mV} = 0.78$

$$P_{COMP} = \int_{-0.78}^{0.78} f_N dx$$

$$P_{COMP} = 2 \bullet F_{N}(0.78) - 1$$



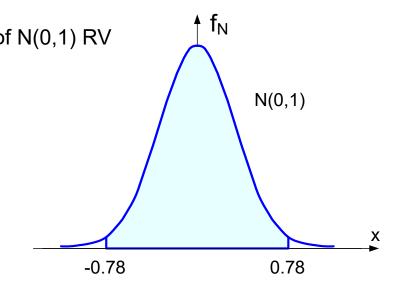
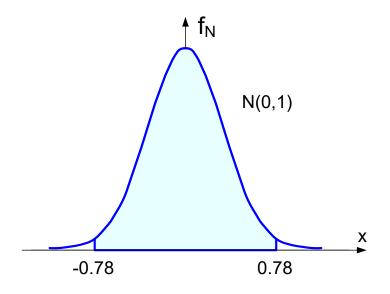


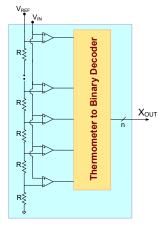
Table of CDF for N(0,1) Random Variables

z z	0.00	0.01	0.02	0.03	0.04	0.05	0.06	0.07	0.08	0.09
0.0	0.5000	0.5040	0.5080	0.5120	0.5160	0.5199	0.5239	0.5279	0.5319	0.5359
0.1	0.5398	0.5438	0.5478	0.5517	0.5557	0.5596	0.5636	0.5675	0.5714	0.5753
0.2	0.5793	0.5832	0.5871	0.5910	0.5948	0.5987	0.6026	0.6064	0.6103	0.6141
0.3	0.6179	0.6217	0.6255	0.6293	0.6331	0.6368	0.6406	0.6443	0.6480	0.6517
0.4	0.6554	0.6591	0.6628	0.6664	0.6700	0.6736	0.6772	0.6808	0.6844	0.6879
0.5	0.6915	0.6950	0.6985	0.7019	0.7054	0.7088	0.7123	0.7157	0.7190	0.7224
0.6	0.7257	0.7291	0.7324	0.7357	0.7389	0.7422	0.7454	0.7486	0.7517	0.7549
0.7	0.7580	0.7611	0.7642	0.7673	0.7703	0.7734	0.7764	0.7794	0.7823	0.7852
0.8	0.7881	0.7910	0.7939	0.7967	0.7995	0.8023	0.8051	0.8078	0.0100	0.8133
0.9	0.8159	0.8186	0.8212	0.8238	0.8264	0.8289	0.8315	0.8340	0.8365	0.8389
1.0	0.8413	0.8438	0.8461	0.8485	0.8508	0.8531	0.8554	0.8577	0.8599	0.8621
1.1	0.8643	0.8665	0.8686	0.8708	0.8729	0.8749	0.8770	0.8790	0.8810	0.8830
1.2	0.8849	0.8869	0.8888	0.8907	0.8925	0.8944	0.8962	0.8980	0.8997	0.90147
1.3	0.90320	0.90490	0.90658	0.90824	0.90988	0.91149	0.91309	0.91466	0.91621	0.91774
1.4	0.91924	0.92073	0.92220	0.92364	0.92507	0.92647	0.92785	0.92922	0.93056	0.93189
1.5	0.93319	0.93448	0.93574	0.93699	0.93822	0.93943	0.94062	0.94179	0.94295	0.94408
1.6	0.94520	0.94630	0.94738	0.94845	0.94950	0.95053	0.95154	0.95254	0.95352	0.95449
1.7	0.95543	0.95637	0.95728	0.95818	0.95907	0.95994	0.96080	0.96164	0.96246	0.96327
1.8	0.96407	0.96485	0.96562	0.96638	0.96712	0.96784	0.96856	0.96926	0.96995	0.97062
1.9	0.97128	0.97193	0.97257	0.97320	0.97381	0.97441	0.97500	0.97558	0.97615	0.97670
2.0	0.97725	0.97778	0.97831	0.97882	0.97932	0.97982	0.98030	0.98077	0.98124	0.98169
2.1	0.98214	0.98257	0.98300	0.98341	0.98382	0.98422	0.98461	0.98500	0.98537	0.98574
2.2	0.98610	0.98645	0.98679	0.98713	0.98745	0.98778	0.98809	0.98840	0.98870	0.98899
2.3	0.98928	0.98956	0.98983	0.9 ² 0097	0.9 ² 0358	$0.9^{2}0613$	$0.9^{2}0863$	0.9 ² 1106	0.9 ² 1344	0.9 ² 1576
2.4	0.9^21802	$0.9^{2}2024$	$0.9^{2}240$	$0.9^{2}2451$	$0.9^{2}2656$	$0.9^{2}2857$	$0.9^{2}3053$	$0.9^{2}3244$	0.9 ² 3431	$0.9^{2}3613$
2.5	0.9^23790	$0.9^{2}3963$	0.9 ² 4132	0.9 ² 4297	0.9 ² 4457	0.9 ² 4614	0.9^24766	0.9 ² 4915	0.9^25060	0.9 ² 5201
2.6	$0.9^{2}5339$	0.9^25473	0.9^25604	0.9 ² 5731	0.9^25855	0.9^25975	$0.9^{2}6093$	$0.9^{2}6207$	0.9 2 6319	$0.9^{2}6427$
2.7	$0.9^{2}6533$	0.9 2 6636	0.9 ² 6736	$0.9^{2}6833$	$0.9^{2}6928$	0.9 ² 7020	0.9 ² 7110	0.9 ² 7197	0.9^27282	0.9 ² 7365
2.8	$0.9^{2}7445$	0.9^27523	0.9^27599	0.9^27673	0.9^27744	0.9^27814	0.9^27882	$0.9^{2}7948$	0.9 ² 8012	0.9^28074
2.9	0.9 ² 8134	0.9 ² 8193	0.928250	0.9^28305	$0.9^{2}8359$	0.9 ² 8411	0.9 ² 8462	0.9 ² 8511	0.9 ² 8559	0.9 ² 8605
3.0	0.9^28650	0.9 ² 8694	0.9 ² 8736	0.9 ² 8777	0.9 ² 8817	0.9 ² 8856	0.9^28893	$0.9^{2}8930$	0.9 ² 8965	$0.9^{2}8999$

Example: 7-bit FLASH ADC with R-string DAC

$$P_{COMP} = 2 \cdot F_{N}(0.78) - 1 = 2 \cdot .7823 - 1 = 0.565$$





Each comparator has 56.5% yield

Example: 7-bit FLASH ADC with R-string DAC

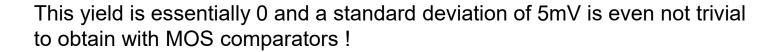
Case 1
$$\sigma_{VOS}$$
=5mV

$$P_{COMP} = 0.565$$

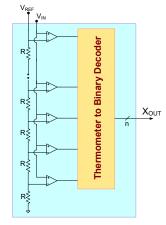
Since all comparators must be good, the ADC yield is

$$Y_{ADC} = (P_{COMP})^{127} = (0.565)^{127}$$

$$Y_{ADC} = 3.2 \cdot 10^{-32}$$



The effects of statistical variation can have dramatic effects on yield of data converters!

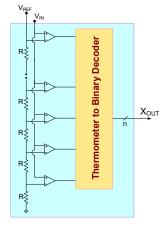


Example: 7-bit FLASH ADC with R-string DAC

Case 1
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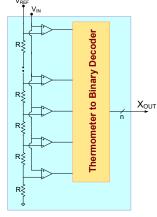


Note: The specification in this example that requires no comparator has an offset voltage of larger than 0.5LSB may not be a good performance specification as the FLASH ADC may actually perform reasonably well even if some comparators have an offset that is larger than 0.5LSB. A more useful requirement might be that there be no bubbles in the thermometer code output. Certainly if all comparators have an offset that is at most 0.5LSB, there will be no bubbles in the output code attributable to comparator offset but a modestly weaker constraint can also guarantee there are no bubbles. With the 0.5LSB assumption, a specification that was dependent upon 127 uncorrelated random variables was obtained which made the analysis quite easy. A "no bubble" specification could be approximated by stating that the maximum of the 127 $V_{\rm OSk}$ - $V_{\rm OSk}$ -1 must be less than $V_{\rm LSB}$. This becomes an order statistic of 127 Gaussian random variables which is analytically intractable.

Example: 7-bit FLASH ADC with R-string DAC

Case 2 Repeat the previous example if σ_{VOS} =1mV

Assume R-string is ideal, V_{REF} =1V and V_{OS} for each comparator must be at most +/- $\frac{1}{2}$ LSB



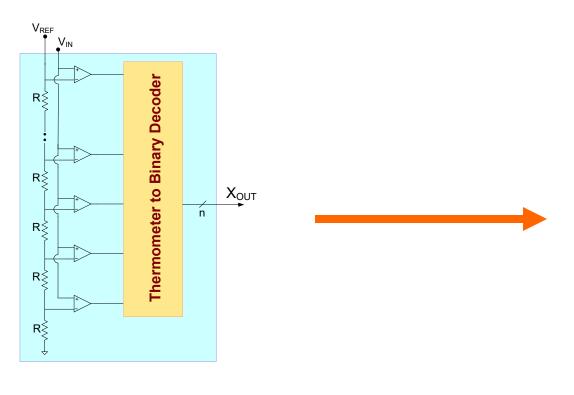
$$P_{COMP} = \int_{-3.9mV}^{3.9mV} f_{VOS}dV \longrightarrow X_{N} = 3.9mV/1mV = 3.9$$

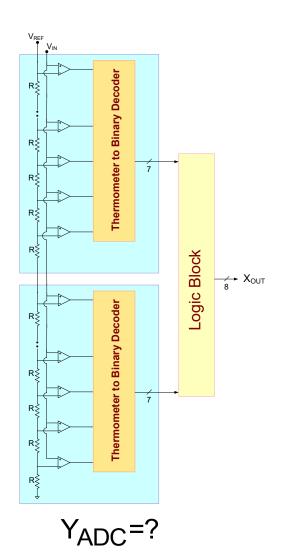
$$P_{COMP} = \int_{-3.9}^{3.9} f_{N}dx \qquad P_{COMP} = 2 \cdot F_{N}(3.9) - 1 = 2 \cdot 0.9999952 - 1 = 0.999904$$

$$Y_{ADC} = (P_{COMP})^{127} = (0.9999904)^{127}$$

This modest change in the offset voltage has increased the yield to 98.8%

Example: What will be the yield if two of the 7-bit FLASH ADCs with yields of 98.8% are combined to obtain an 8-bit ADC?





Example: What will be the yield if two of the 7-bit FLASH ADCs with yields of 98.8% are combined to obtain an 8-bit ADC?

Since one additional bit has been added, V_{LSB} will decrease From 7.8mV to 3.9mV. Thus ½ LSB will be reduced to 1.95mV

$$P_{COMP} = \int_{-1.95mV}^{1.95mV} f_{VOS} dV$$

With the same σ_{VOS} =1mV,

$$X_N = 1.95 \text{mV} / 1 \text{mV} = 1.95$$

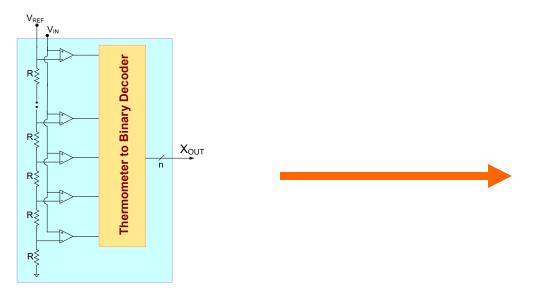
$$P_{COMP} = \int_{-1.95}^{1.95} f_{N} dx \qquad P_{COMP} = 2 \bullet F_{N} (1.95) - 1 = 2 \bullet 0.97441 - 1 = 0.9488$$

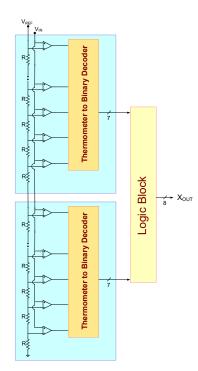
$$Y_{ADC} = (P_{COMP})^{255} = (0.9488)^{255}$$

$$Y_{ADC} = 1.52 \bullet 10^{-6}$$

This seemingly simple extension of a circuit with a very high yield has essentially no yield!

Example: What will be the yield if two of the 7-bit FLASH ADCs with yields of 98.8% are combined to obtain an 8-bit ADC?





$$Y_{ADC} = 1.52 \cdot 10^{-6}$$

- The onset of statistically-induced yield loss can be abrupt
- Intuition is not an acceptable substitute to statistical analysis
- Without statistical analysis/simulation there is a high probability that a data converter will be substantially over designed or under designed and neither is acceptable

Statistical Modeling of Random Variations

For the effects of local random variations of a parameter X, generally

$$\sigma_{X} \propto \frac{A_0}{\sqrt{A_C}}$$

where A_C is the area of the matching critical components and A₀ is a process parameter

Importance of statistical analysis – example

What changes in area would be needed to decrease σ_{VOS} from 5mV to 1mV?

$$\sigma_{X} \propto \frac{A_0}{\sqrt{A_C}}$$

$$\sigma_{X_{5}} = \theta \frac{A_{0}}{\sqrt{A_{C_{5}}}}$$

$$\sigma_{X_{1}} = \theta \frac{A_{0}}{\sqrt{A_{C_{1}}}}$$

$$\frac{\sigma_{X_5}}{\sigma_{X_1}} = \frac{\sqrt{A_{C_1}}}{\sqrt{A_{C_5}}} = 5$$

$$\mathsf{A}_{\mathsf{C}_1} = 25 \mathsf{A}_{\mathsf{C}_5}$$

Equivalent Number of Bits (ENOB)

- Often the performance of an n-bit commercial data converter is not commensurate with that of an ideal n-bit data converter but more like that of an n-k bit data converter
- The equivalent number of bits (ENOB) is often used to characterize the actual level of performance
- Different ENOB definitions depending upon which characterization parameter is of interest (e.g. INL, SFDR, SNR, ...)

INL-based ENOB

(Review from Lecture 27 Spring 2023)

Consider initially the continuous INL definition for an ADC where the INL of an ideal ADC is $X_{LSB}/2$

Assume INL=
$$vX_{LSBR} = v\frac{X_{REF}}{2^{n_R}}$$

where X_{LSBR} is the LSB based upon the defined resolution , n_{R}

Define the equivalent LSB by
$$X_{LSBE} = \frac{X_{REF}}{2^{n_{EQ}}}$$

Thus (substituting for X_{RFF} into INL expression):

INL=
$$v \frac{2^{n_{EQ}}}{2^{n_{R}}} X_{LSBE} = \left[v 2^{n_{EQ}+1-n_{R}}\right] \frac{X_{LSBE}}{2}$$

Since an ideal ADC has an INL of $X_{LSB}/2$, Setting term in [] to 1, can solve for n_{EQ} to obtain

ENOB =
$$n_{EQ} = log_2 \left(\frac{1}{2\theta}\right) = n_R - 1 - log_2(\upsilon)$$

where n_R is the defined resolution

(Review from Lecture 27 Spring 2023)

INL-based ENOB

ENOB = n_R -1- $log_2(v)$

Consider an ADC with specified resolution of n_R and INL of v LSB

V	ENOB
1/2	n _R
1	n _R -1
2	n _R -2
4	n _R -3
8	n _R -4
16	n _R -5

Though based upon the continuous-INL definition, often used to define ENOB from INL viewpoint



16-Bit, 200 MSPS/250 MSPS Analog-to-Digital Converter

Data Sheet \$120 in 1000's AD9467

FEATURES

75.5 dBFS SNR to 210 MHz at 250 MSPS
90 dBFS SFDR to 300 MHz at 250 MSPS
SFDR at 170 MHz at 250 MSPS
92 dBFS at -1 dBFS
100 dBFS at -2 dBFS
60 fs rms jitter
Excellent linearity at 250 MSPS

 $DNL = \pm 0.5 LSB typical$

INL = ±3.5 LSB typical

2V-p-p to 2.5 V p-p (default) differential full-scale

input (programmable)

Integrated input buffer

External reference support option

Clock duty cycle stabilizer

Output clock available

Serial port control

Built-in selectable digital test pattern generation

Selectable output data format

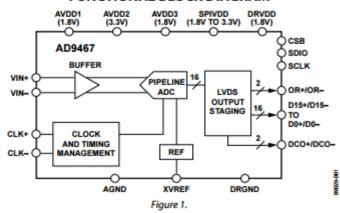
LVDS outputs (ANSI-644 compatible)

1.8 V and 3.3 V supply operation

APPLICATIONS

Multicarrier, multimode cellular receivers
Antenna array positioning
Power amplifier linearization
Broadband wireless
Radar
Infrared imaging
Communications instrumentation

FUNCTIONAL BLOCK DIAGRAM



ENOB = n_R -1- $\log_2(v)$ = $16-1-1.85 \cong 13.15$

Is this close to 16-bit performance?

A data clock output (DCO) for capturing data on the output is provided for signaling a new output bit.

The internal power-down feature supported via the SPI typically consumes less than 5 mW when disabled.

Optional features allow users to implement various selectable operating conditions, including input range, data format select, and output data test patterns.

The AD9467 is available in a Pb-free, 72-lead, LFCSP specified over the -40°C to +85°C industrial temperature range.

Can we depend on this "13-bit" INL performance?

SPECIFICATIONS

AVDD1 = 1.8 V, AVDD2 = 3.3 V, AVDD3 = 1.8 V, DRVDD = 1.8 V, specified maximum sampling rate, 2.5 V p-p differential input, 1.25 V internal reference, AIN = -1.0 dBFS, DCS on, default SPI settings, unless otherwise noted.

Table 1.

Parameter ¹	Temp	Min	Тур	Max	Unit
RESOLUTION		16			Bits
ACCURACY					
No Missing Codes	Full		Guaranteed		
Offset Error	Full	-200	0	+200	LSB
Gain Error	Full	-3.9	-0.1	+2.6	%FSR
Differential Nonlinearity (DNL) ²	Full	-0.9	±0.5	+15	LSB
Integral Nonlinearity (INL) ²	Full (-12	±3.5	+12	LSB
TEMPERATURE DRIFT					/
Offset Error	Full		±0.023		%FSR/°C
Gain Error	Full		±0.036		%FSR/°C
ANALOG INPUTS					
Differential Input Voltage Range (Internal VREF = 1 V to 1.25 V)	Full	2	2.5	2.5	V p-p
Common-Mode Voltage	25°C		2.15		V
Differential Input Resistance	25°C		530		Ω
Differential Input Capacitance	25°C		3.5		pF
Full Power Bandwidth	25°C		900		MHz
XVREF INPUT					
Input Voltage	Full	1		1.25	V
Input Capacitance	Full		3		pF
POWER SUPPLY					
AVDD1	Full	1.75	1.8	1.85	V
AVDD2	Full	3.0	3.3	3.6	V
AVDD3	Full	1.7	1.8	1.9	V
DRVDD	Full	1.7	1.8	1.9	V
I _{AVDD1}	Full		567	620	mA
I _{AVDD2}	Full		55	61	mA
I _{AVDD3}	Full		31	35	mA
I _{DRVDD}	Full		40	43	mA
Total Power Dissipation (Including Output Drivers)	Full		1.33	1.5	W
Power-Down Dissipation	Full		4.4	90	mW

¹ See the AN-835 Application Note, Understanding High Speed ADC Testing and Evaluation, for a complete set of definitions and how these tests were completed.

ENOB =
$$n_R$$
-1- $\log_2(v)$ = $16-1-3.58 \cong 11.42$

From INL viewpoint, performance of marketed parts could be about 4.5 bits less than physical resolution but does have other attractive properties

² Measured with a low input frequency, full-scale sine wave, with approximately 5 pF loading on each output bit.

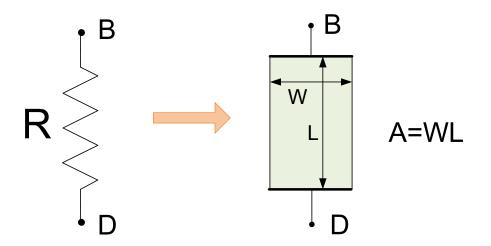
AC SPECIFICATIONS

AVDD1 = 1.8 V, AVDD2 = 3.3 V, AVDD3 = 1.8 V, DRVDD = 1.8 V, specified maximum sampling rate, 2.5 V p-p differential input, 1.25 V internal reference, AIN = -1.0 dBFS, DCS on, default SPI settings, unless otherwise noted.

Table 2.

Parameter ¹	Temp	Min	Тур	Max	Unit
ANALOG INPUT FULL SCALE		2.5	2/2.5		V p-p
SIGNAL-TO-NOISE RATIO (SNR)					
$f_N = 5 \text{ MHz}$	25°C		74.7/76.4		dBF5
f _N = 97 MHz	25°C		74.5/76.1		dBF5
$f_N = 140 \text{ MHz}$	25°C		74.4/76.0		dBF:
$f_N = 170 \text{ MHz}$	25°C	73.7	74.3/75.8		dBF5
	Full	71.5			dBF5
f _N = 210 MHz	25°C		74.0/75.5		dBF:
$f_N = 300 \text{ MHz}$	25°C		73.3/74.6		dBF5
SIGNAL-TO-NOISE AND DISTORTION RATIO (SINAD)					
f _N = 5 MHz	25°C		74.6/76.3		dBF5
f _N = 97 MHz	25°C		74.4/76.0		dBF5
f _N = 140 MHz	25°C		74.4/76.0		dBF
f _N = 170 MHz	25°C	72.4	74.2/75.8		dBF
	Full	71.0			dBF
f _{IN} = 210 MHz	25°C	7	73.9/75.4		dBF
fn = 300 MHz	25°C		73.1/74.4		dBF:
EFFECTIVE NUMBER OF BITS (ENOB)			73.1,7 1.1		ubi .
5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5 5	25°C		12.1/12.4		Bits
t _{N=97MHz} • Can be defined different ways	25°C		12.1/12.4		Bits
5 440 MH-	25°C		12.1/12.3		Bits
f _{N=170 MHz} • Only given as typical	25°C		12.1/12.3		Bits
	Full	11.5	12.0/12.3		Bits
_{f_N=210 MHz} • Only specified at 25C	25°C	11.5	12.0/12.2		Bits
f _N = 300 MHz	25°C		11.9/12.1		Bits
SPURIOUS-FREE DYNAMIC RANGE (SFDR) (INCLUDING SECOND AND THIRD HARMONIC DISTORTION)	25 C		11.9/12.1		DILS
fin = 5 MHz	25°C		98/97		dBF:
fn=97 MHz	25°C		95/93		dBF
f _N = 140 MHz	25°C		93/93		dBF:
f _N = 170 MHz	25°C	00			
TN = 1/0 MMZ		82 82	93/92		dBF5
£ 210.HU	Full	82	03/03		
f _N = 210 MHz	25°C		93/92		dBF:
f _N = 300 MHz	25°C		93/90		dBF:
SFDR (INCLUDING SECOND AND THIRD HARMONIC DISTORTION)					
fin = 5 MHz at -2 dB Full Scale	25°C		100/100		dBF:
f _N = 97 MHz at -2 dB Full Scale	25°C		97/97		dBF:
f _N = 140 MHz at-2 dB Full Scale	25°C		100/95		dBF:
f _N = 170 MHz at -2 dB Full Scale	25°C		100/100		dBF:
f _N = 210 MHz at −2 dB Full Scale	25°C		93/93		dBF:
f _N = 300 MHz at -2 dB Full Scale	25°C		90/90		dBF:
WORST OTHER (EXCLUDING SECOND AND THIRD HARMONIC DISTORTION)					
f _N = 5 MHz	25°C		98/97		dBF5
$f_N = 97 \text{MHz}$	25°C		97/93		dBF:
$f_N = 140 \text{ MHz}$	25°C		97/95		dBF:
$f_N = 170 \text{ MHz}$	25°C	88	97/93		dBF:
	Full	82			dBF5
$f_N = 210 \text{ MHz}$	25°C		97/95		dBF
f _N = 300 MHz	25°C	l	97/95		dBF5

Statistical Characterization of Resistors



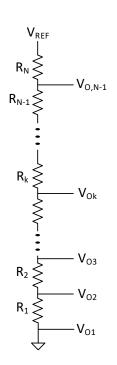
$$\sigma_{\frac{R}{R_N}} = \frac{A_R}{\sqrt{WL}} = \frac{A_R}{\sqrt{A}}$$

A_R is a process parameter

Note the normalized variance is independent of the resistor value!

Ratio Matching Effects in Data Converters

- Ratio matching is often critical in ADCs and DACs
- Accuracy and matching of gains is also critical in some data converters



Recall
$$INL_k = V_{OUT}(k) - V_{FIT}(k)$$

 $0 \le k \le N-1$

- INL is of considerable interest
- INL=Max($|INL_k|$), 0<k<N-1
- INL is difficult to characterize analytically so will focus on INL_k

Assume resistors are uncorrelated RVs but identically distributed, typically zero mean Gaussian

It can be shown that INLk is zero-mean gaussian and

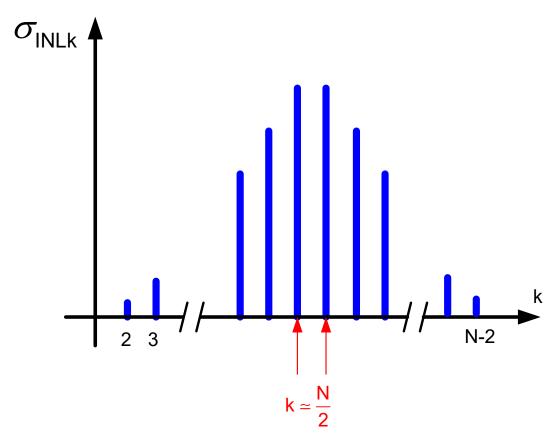
$$\sigma_{INL_{k}} = \sigma_{\frac{R_{R}}{R_{N}}} \sqrt{\frac{(N-k)(k-1)}{N-1}}$$

Note this is a nice closed-form expression for the standard deviation of INL_k for a string DAC !!

Observe this assumes a maximum value at about k=N/2

$$\sigma_{\text{INL}_k\text{MAX}} \simeq \sigma_{\frac{R_R}{R_N}} \sqrt{\frac{\left(N - \frac{N}{2}\right)\!\left(\frac{N}{2} - 1\right)}{N - 1}} \simeq \sigma_{\frac{R_R}{R_N}} \frac{\sqrt{N}}{2}$$

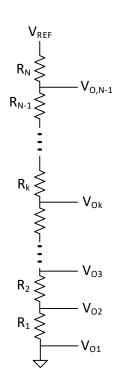
standard deviation of INL_k assumes a maximum variance at mid-code



Recall INL_k is Gaussian and

$$\sigma_{INLk \max} = \sigma_{\frac{R_R}{R_{NOM}}} \frac{\sqrt{N}}{2}$$

Example 1:

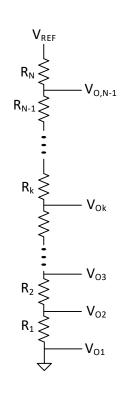


Assume specification for 7-bit String DAC $|INL_{kMAX}|$ <1 LSB and Pelgrom matching parameter A_{ρ} = 0.1 μ m

Desired Yield Y = 99%

Determine the resistor area A to achieve this yield

Determine the resistor area A to achieve this yield



Define
$$z = INL_{kMAX}$$

$$z: N(0 \sigma_z)$$

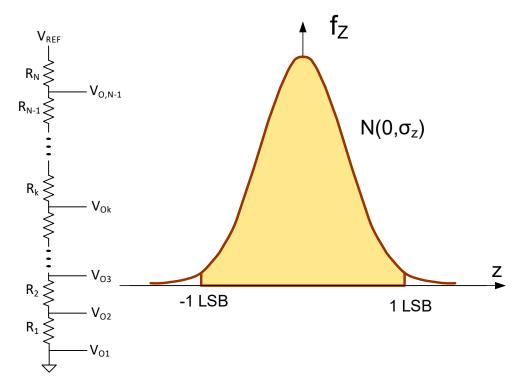
z:
$$N(0 \sigma_z)$$

$$\sigma_z \simeq \sigma_{\frac{R}{R_N}} \bullet \frac{\sqrt{N}}{2}$$

Assume f_z is the PDF of z

Solution strategy: Obtain σ_z , then solve above equation for and then solve $\sigma_{\frac{R}{R_N}}$ for A: $\sigma_{\frac{R}{R_N}} = \frac{A_R}{\sqrt{WL}} = \frac{A_R}{\sqrt{A}}$

Determine the resistor area A to achieve this yield



Want to determine A so that

$$0.99 = \int_{-1LSB}^{1LSB} f_z(z) dz$$

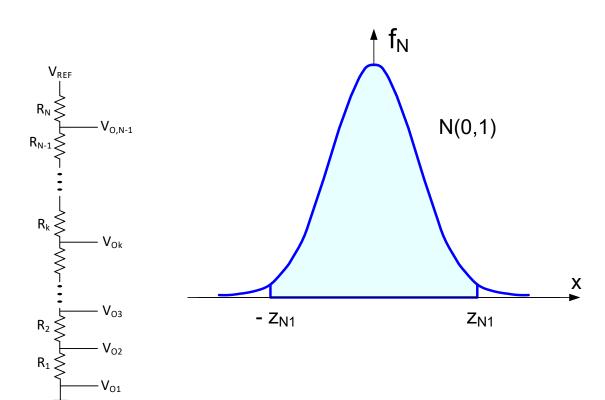
Define: $z_N = \frac{z}{\sigma_z} \qquad z_{N1} = \frac{1 LSB}{\sigma_z}$ $z_N \sim N \big(0,1 \big)$

Notation: pdf of z_N is $f_N(z_N)$

By change of variables, want

$$0.99 = \int\limits_{-Z_{N1}}^{z_{N1}} f_N(z) dz$$

Determine the resistor area A to achieve this yield

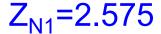


$$0.99 = \int\limits_{-Z_{N1}}^{z_{N1}} f_N(z) dz$$

$$0.99 = 2F_N(z_{N1}) - 1$$

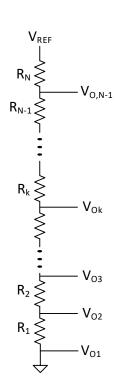
$$F_N(z_{N1}) = 0.995$$

$$F_N(z_{N1}) = 0.995$$
 $Z_{N1} = 2.575$



										_
√z Z	0.00	0.01	0.02	0.03	0.04	0.05	0.06	0.07	0.08	0.09
0.0	0.5000	0.5040	0.5080	0.5120	0.5160	0.5199	0.5239	0.5279	0.5319	0.5359
0.1	0.5398	0.5438	0.5478	0.5517	0.5557	0.5596	0.5636	0.5675	0.5714	0.5753
0.2	0.5793	0.5832	0.5871	0.5910	0.5948	0.5987	0.6026	0.6064	0.6103	0.6141
0.3	0.6179	0.6217	0.6255	0.6293	0.6331	0.6368	0.6406	0.6443	0.6480	0.6517
0.4	0.6554	0.6591	0.6628	0.6664	0.6700	0.6736	0.6772	0.6808	0.6844	0.6879
0.5	0.6915	0.6950	0.6985	0.7019	0.7054	0.7088	0.7123	0.7157	0.7190	0.7224
0.6	0.7257	0.7291	0.7324	0.7357	0.7389	0.7422	0.7454	0.7486	0.7517	0.7549
0.7	0.7580	0.7611	0.7642	0.7673	0.7703	0.7734	0.7764	0.7794	0.7823	0.7852
8.0	0.7881	0.7910	0.7939	0.7967	0.7995	0.8023	0.8051	0.8078	0.8106	0.8133
0.9	0.8159	0.8186	0.8212	0.8238	0.8264	0.8289	0.8315	0.8340	0.8365	0.8389
1.0	0.8413	0.8438	0.8461	0.8485	0.8508	0.8531	0.8554	0.8577	0.8599	0.8621
1.1	0.8643	0.8665	0.8686	0.8708	0.8729	0.8749	0.8770	0.8790	0.8810	0.8830
1.2	0.8849	0.8869	0.8888	0.8907	0.8925	0.8944	0.8962	0.8980	0.8997	0.90147
1.3	0.90320	0.90490	0.90658	0.90824	0.90988	0.91149	0.91309	0.91466	0.91621	0.91774
1.4	0.91924	0.92073	0.92220	0.92364	0.92507	0.92647	0.92785	0.92922	0.93056	0.93189
1.5	0.93319	0.93448	0.93574	0.93699	0.93822	0.93943	0.94062	0.94179	0.94295	0.94408
1.6	0.94520	0.94630	0.94738	0.94845	0.94950	0.95053	0.95154	0.95254	0.95352	0.95449
1.7	0.95543	0.95637	0.95728	0.95818	0.95907	0.95994	0.96080	0.96164	0.96246	0.96327
1.8	0.96407	0.96485	0.96562	0.96638	0.96712	0.96784	0.96856	0.96926	0.96995	0.97062
1.9	0.97128	0.97193	0.97257	0.97320	0.97381	0.97441	0.97500	0.97558	0.97615	0.97670
2.0	0.97725	0.97778	0.97831	0.97882	0.97932	0.97982	0.98030	0.98077	0.98124	0.98169
2.1	0.98214	0.98257	0.98300	0.98341	0.98382	0.98422	0.98461	0.98500	0.98537	0.98574
2.2	0.98610	0.98645	0.98679	0.98713	0.98745	0.98778	0.98809	0.98840	0.98870	0.98899
2.3	0.98928	0.98956	0.98983	$0.9^{2}0097$	$0.9^{2}0358$	$0.9^{2}0613$	$0.9^{2}0863$	0.9 ² 1106	0.9 ² 1344	0.9 ² 1576
2.4	0.9^21802	$0.9^{2}2024$	0.9 ² 2240	0.9 ² 2451	$0.9^{2}2656$	0.9 ² 2857	$0.9^{2}3053$	$0.9^{2}3244$	0.022421	0.9 ² 3613
2.5	0.9 ² 3790	$0.9^{2}3963$	0.9 ² 4132	$0.9^{2}4297$	$0.9^{2}4457$	$0.9^{2}4614$	$0.9^{2}4766$	0.9 ² 4915	0.9^25060	0.9 ² 5201
2.6	0.9 ² 5339	$0.9^{2}5473$	0.9^25604	0.9 ² 5731	0.9^25855	0.9^25975	$0.9^{2}6093$	$0.9^{2}6207$	0.9°6319	0.9 ² 6427
2.7	$0.9^{2}6533$	$0.9^{2}6636$	$0.9^{2}6736$	$0.9^{2}6833$	$0.9^{2}6928$	0.9^27020	0.927110	0.9 ² 7197	$0.9^{2}7282$	0.9 ² 7365
2.8	$0.9^{2}7445$	$0.9^{2}7523$	0.9^27599	0.927673	0.9^27744	0.9 ² 7814	0.9^27882	0.9 ² 7948	0.9 ² 8012	0.9 ² 8074
2.9	0.9^28134	0.928193	$0.9^{2}8250$	$0.9^{2}8305$	$0.9^{2}8359$	0.9 ² 8411	$0.9^{2}8462$	0.9 ² 8511	$0.9^{2}8559$	0.9^28605
3.0	0.9^28650	$0.9^{2}8694$	$0.9^{2}8736$	0.9 ² 8777	0.9 ² 8817	$0.9^{2}8856$	$0.9^{2}8893$	$0.9^{2}8930$	$0.9^{2}8965$	$0.9^{2}8999$
				1				^	1	

Determine the resistor area A to achieve this yield



$$Z_{N1}=2.575$$

$$Z_{N1}=\frac{1LSB}{\sigma_{Z}}$$

$$\sigma_{z}=0.388$$

but
$$\sigma_z = \sigma_{\frac{R}{R_N}} \bullet \frac{\sqrt{N}}{2} = \frac{A_{\rho}}{\sqrt{A}} \bullet \frac{\sqrt{N}}{2}$$

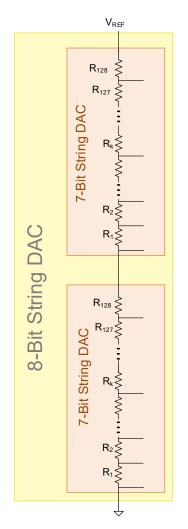
$$0.388 = \frac{A_{\rho}}{\sqrt{A}} \bullet \frac{\sqrt{N}}{2} \qquad \qquad \text{N = 127 and } A_{\rho} = 0.1 \ \mu\text{m}$$

Solving, obtain

$$A = 2.13 \ \mu m^2$$
 $\sigma_{\frac{R}{R_N}} = 0.0685$

Example 2: Consider an 8-bit DAC obtained by combining 2 of the 7-bit DACs

Determine the yield if the specification is still |INL_{kMAX}| <1LSB



Define $z = INL_{kMAX}$

$$\sigma_z = \sigma_{\frac{R}{R_N}} \bullet \frac{\sqrt{N}}{2}$$

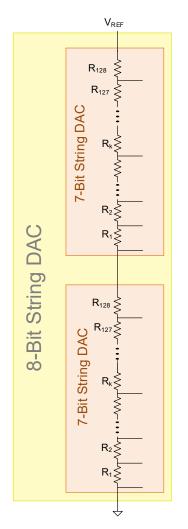
Since same resistors are used, $\sigma_{\frac{R}{R_N}} = 0.0685$

$$\sigma_z = 0.0685 \bullet \frac{\sqrt{256}}{2} = 0.5488$$

$$Y = \int_{-1LSB}^{1LSB} f_z(z) dz$$

Example 2: Consider an 8-bit DAC obtained by combining 2 of the 7-bit DACs

Determine the yield if the specification is still |INL_{kMAX}| <1LSB

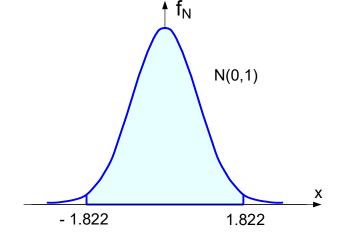


$$Y = \int_{-1LSB}^{1LSB} f_z(z) dz$$

Define
$$z_N = \frac{z}{\sigma_z}$$

$$z_N = \frac{1LSB}{0.5488} = 1.822$$

$$Y = 2F_N(1.822) - 1$$

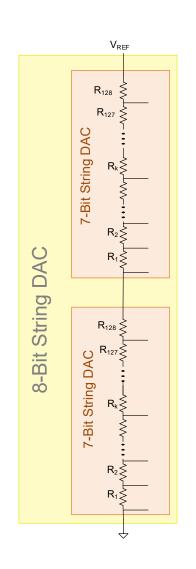


F(0.822) = 0.9656

Z Z	0.00	0.01	0.02	0.03	0.04	0.05	0.06	0.07	0.08	0.09
0.0	0.5000	0.5040	0.5080	0.5120	0.5160	0.5199	0.5239	0.5279	0.5319	0.5359
0.1	0.5398	0.5438	0.5478	0.5517	0.5557	0.5596	0.5636	0.5675	0.5714	0.5753
0.2	0.5793	0.5832	0.5871	0.5910	0.5948	0.5987	0.6026	0.6064	0.6103	0.6141
0.3	0.6179	0.6217	0.6255	0.6293	0.6331	0.6368	0.6406	0.6443	0.6480	0.6517
0.4	0.6554	0.6591	0.6628	0.6664	0.6700	0.6736	0.6772	0.6808	0.6844	0.6879
0.5	0.6915	0.6950	0.6985	0.7019	0.7054	0.7088	0.7123	0.7157	0.7190	0.7224
0.6	0.7257	0.7291	0.7324	0.7357	0.7389	0.7422	0.7454	0.7486	0.7517	0.7549
0.7	0.7580	0.7611	0.7642	0.7673	0.7703	0.7734	0.7764	0.7794	0.7823	0.7852
8.0	0.7881	0.7910	0.7939	0.7967	0.7995	0.8023	0.8051	0.8078	0.8106	0.8133
0.9	0.8159	0.8186	0.8212	0.8238	0.8264	0.8289	0.8315	0.8340	0.8365	0.8389
1.0	0.8413	0.8438	0.8461	0.8485	0.8508	0.8531	0.8554	0.8577	0.8599	0.8621
1.1	0.8643	0.8665	0.8686	0.8708	0.8729	0.8749	0.8770	0.8790	0.8810	0.8830
1.2	0.8849	0.8869	0.8888	0.8907	0.8925	0.8944	0.8962	0.8980	0.8997	0.90147
1.3	0.90320	0.90490	0.90658	0.90824	0.90988	0.91149	0.91309	0.91466	0.91621	0.91774
1.4	0.91924	0.92073	0.92220	0.92364	0.92507	0.92647	0.92785	0.92922	0.93056	0.93189
1.5	0.93319	0.93448	0.93574	0.93699	0.93822	0.93943	0.94062	0.94179	0.94295	0.94408
1.6	0.94520	0.94630	0.94738	0.94845	0.94950	0.95053	0.95154	0.95254	0.95352	0.95449
1.7	0.95543	0.95637	0.95728	0.95818	0.95907	0.95994	0.96080	0.96164	0.96246	0.96327
1.8	0.96407	0.96485	0.96562	0.96638	0.96712	0.96784	0.96856	0.96926	0.96995	0.97062
1.9	0.97128	0.97193	0.07257	0.97320	0.97381	0.97441	0.97500	0.97558	0.97615	0.97670
2.0	0.97725	0.97778	0.97831	0.97882	0.97932	0.97982	0.98030	0.98077	0.98124	0.98169
2.1	0.98214	0.98257	0.98300	0.98341	0.98382	0.98422	0.98461	0.98500	0.98537	0.98574
2.2	0.98610	0.98645	0.98679	0.98713	0.98745	0.98778	0.98809	0.98840	0.98870	0.98899
2.3	0.98928	0.98956	0.98983	$0.9^{2}0097$	$0.9^{2}0358$	0.9 ² 0613	$0.9^{2}0863$	0.9 ² 1106	0.9 ² 1344	0.9 ² 1576
2.4	0.9^21802	$0.9^{2}2024$	$0.9^{2}240$	0.9 ² 2451	$0.9^{2}2656$	$0.9^{2}2857$	$0.9^{2}3053$	$0.9^{2}3244$	0.9 ² 3431	0.9 ² 3613
2.5	0.9^23790	$0.9^{2}3963$	0.9 ² 4132	$0.9^{2}4297$	$0.9^{2}4457$	$0.9^{2}4614$	$0.9^{2}4766$	0.9 ² 4915	0.9^25060	0.9 ² 5201
2.6	$0.9^{2}5339$	0.9^25473	0.9^25604	0.9 ² 5731	0.9^25855	0.9^25975	$0.9^{2}6093$	$0.9^{2}6207$	0.9 ² 6319	$0.9^{2}6427$
2.7	$0.9^{2}6533$	0.926636	$0.9^{2}6736$	$0.9^{2}6833$	$0.9^{2}6928$	$0.9^{2}7020$	0.9 ² 7110	0.927197	$0.9^{2}7282$	$0.9^{2}7365$
2.8	$0.9^{2}7445$	0.9^27523	0.9^27599	0.927673	0.9^27744	0.9 ² 7814	0.9^27882	0.9 ² 7948	0.9 ² 8012	0.9^28074
2.9	$0.9^{2}8134$	0.928193	$0.9^{2}8250$	$0.9^{2}8305$	$0.9^{2}8359$	0.9 ² 8411	$0.9^{2}8462$	0.9 ² 8511	$0.9^{2}8559$	$0.9^{2}8605$
3.0	0.9 ² 8650	0.9 ² 8694	0.9 ² 8736	0.9 ² 8777	0.9 ² 8817	0.9 ² 8856	0.9 ² 8893	0.9 ² 8930	0.9 ² 8965	0.9 ² 8999

Example 2:

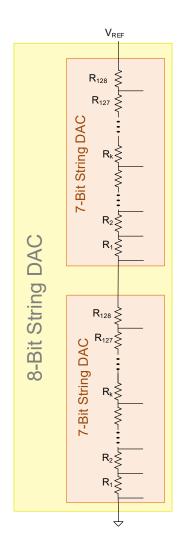
Consider an 8-bit DAC obtained by combining 2 of the 7-bit DACs



$$Y = 2F_N (1.822) - 1$$

 $Y = 2 \cdot 0.965 - 1 = 0.93$

Yield has dropped from 99% to 93%



Example 3: What area is needed for obtaining a 99% yield for an 8-bit string DAC and how does that compare to the area required for a 7-bit DAC with the same yield?

For 99% yield
$$\sigma_z = \sigma_{\frac{R}{R_N}} \bullet \frac{\sqrt{N}}{2} = \frac{A_\rho}{\sqrt{A}} \bullet \frac{\sqrt{N}}{2} = 0.388$$

$$\frac{A_\rho}{\sqrt{A}} \bullet \frac{\sqrt{N}}{2} = 0.388$$

$$A_\rho = 0.1 \mu m \qquad N = 256$$

$$A = 4.25 \mu m^2$$

Area doubled because there are twice as many resistors and each is approximately twice as big so by adding 1-bit of resolution, the area went up by approximately a factor of 4

How about statistics for the INL?

$$INL = \max_{1 \le k \le N} |INL_k|$$

$$INL_{k} = \frac{1}{R_{NOM}} \left[\sum_{j=1}^{k} R_{Rj} \left(1 - \frac{k}{N-1} \right) - \frac{k}{N-1} \sum_{j=k+1}^{N-1} R_{Rj} \right] \qquad 1 \le k \le N-1$$

- INL is an order statistic
- Distribution functions for order statistics are very complicated and closed form solutions do not exist!
- INL is not zero-mean and not Gaussian
- Statistical simulations using Monte-Carlo analysis often used to predict INL yield but these simulations can be extremely time consuming if the order of the data converter is very large

- Statistical analysis of data converters is critical
- Some architectures are more sensitive than others to statistical variations in components
- The onset of yield loss due to statistical limitations is generally quite abrupt and can have disastrous effects if not considered as part of the design process

Recall examples where σ_{VOS} =5mV compared with σ_{VOS} =1mV

 Substantially over-designing to avoid concerns about statistical yield loss is not a practical solution since the area penalty, the speed penalty, and the power penalty are generally quite severe

For the effects of local random variations of a parameter X, generally

$$\sigma_X \propto \frac{A_0}{\sqrt{A_C}}$$

where A_C is the area of the matching critical components and A₀ is a process parameter



Stay Safe and Stay Healthy!

End of Lecture 39